

# 6MBP50VAA060-50

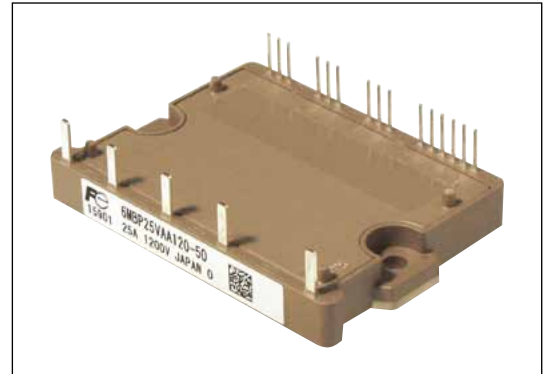
IGBT Modules

## IGBT MODULE (V series)

### 600V / 50A / IPM

#### ■ Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- Compatible with existing IPM-N series packages
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



#### ■ Maximum Ratings and Characteristics

##### ● Absolute Maximum Ratings (T<sub>c</sub>=25°C, V<sub>cc</sub>=15V unless otherwise specified)

Items	Symbol	Min.	Max.	Units
Collector-Emitter Voltage (*1)	V <sub>CEs</sub>	0	600	V
Short Circuit Voltage	V <sub>sc</sub>	200	400	V
Collector Current	DC	I <sub>c</sub>	50	A
	1ms	I <sub>c</sub> pulse	100	A
	Duty=100% (*2)	-I <sub>c</sub>	50	A
Collector Power Dissipation	1 device (*3)	P <sub>c</sub>	192	W
Supply Voltage of Pre-Driver (*4)	V <sub>cc</sub>	-0.5	20	V
Input Signal Voltage (*5)	V <sub>in</sub>	-0.5	V <sub>cc</sub> +0.5	V
Alarm Signal Voltage (*6)	V <sub>ALM</sub>	-0.5	V <sub>cc</sub>	V
Alarm Signal Current (*7)	I <sub>ALM</sub>	-	20	mA
Junction Temperature	T <sub>j</sub>	-	150	°C
Operating Case Temperature	T <sub>opr</sub>	-20	110	°C
Storage Temperature	T <sub>stg</sub>	-40	125	°C
Solder Temperature (*8)	T <sub>sol</sub>	-	260	°C
Isolating Voltage (*9)	V <sub>iso</sub>	-	AC2500	V <sub>rms</sub>
Screw Torque	Mounting (M4)	-	1.7	Nm

Note \*1: V<sub>CEs</sub> shall be applied to the input voltage between terminal P-(U,V, W) and (U,V, W)-N.

Note \*2: Duty=125°C/R<sub>th(j-c)</sub>D/(I<sub>F</sub>×V<sub>F</sub> Max.)×100

Note \*3: P<sub>c</sub>=125°C/R<sub>th(j-c)</sub>Q

Note \*4: V<sub>cc</sub> shall be applied to the input voltage between terminal No.3 and 1, 6 and 4, 9 and 7, 11 and 10.

Note \*5: V<sub>in</sub> shall be applied to the input voltage between terminal No.2 and 1, 5 and 4, 8 and 7, 12~14 and 10.

Note \*6: V<sub>ALM</sub> shall be applied to the voltage between terminal No.15 and 10.

Note \*7: I<sub>ALM</sub> shall be applied to the input current to terminal No.15.

Note \*8: Immersion time 10±1sec. 1time.

Note \*9: Terminal to base, 50/60Hz sine wave 1minute.

● Electrical Characteristics (T<sub>j</sub>=25°C, V<sub>cc</sub>=15V unless otherwise specified)

Items	Symbol	Conditions	Min.	Typ.	Max.	Units		
Inverter	Collector Current at off signal input	I <sub>CEs</sub>	V <sub>CE</sub> =600V	-	-	1.0	mA	
	Collector-Emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>c</sub> =50A	Terminal	-	-	2.0	V
				Chip	-	1.4	-	V
	Forward voltage of FWD	V <sub>F</sub>	I <sub>F</sub> =50A	Terminal	-	-	2.3	V
Chip				-	1.8	-	V	
Switching time	t <sub>on</sub>	V <sub>DC</sub> =300V, T <sub>j</sub> =125°C	1.1	-	-	μs		
	t <sub>off</sub>	I <sub>c</sub> =50A	-	-	2.1	μs		
	t <sub>rr</sub>	V <sub>DC</sub> =300V I <sub>F</sub> =50A	-	-	0.3	μs		
Supply current of P-side pre-driver (per one unit)	I <sub>ccp</sub>	Switching Frequency= 0-15kHz	-	-	10	mA		
Supply current of N-side pre-driver	I <sub>ccn</sub>	T <sub>c</sub> =-20~110°C	-	-	25	mA		
Input signal threshold voltage	V <sub>inH(on)</sub>	Vin-GND	ON	1.2	1.4	1.6	V	
	V <sub>inH(off)</sub>		OFF	1.5	1.7	1.9	V	
Over Current Protection Level	I <sub>oc</sub>	T <sub>j</sub> =125°C	75	-	-	A		
Over Current Protection Delay time	t <sub>ΔOC</sub>	T <sub>j</sub> =125°C	-	5	-	μs		
Short Circuit Protection Delay time	t <sub>sc</sub>	T <sub>j</sub> =125°C	-	2	3	μs		
IGBT Chips Over Heating Protection Temperature Level	T <sub>JOH</sub>	Surface of IGBT Chips	150	-	-	°C		
Over Heating Protection Hysteresis	T <sub>JH</sub>		-	20	-	°C		
Under Voltage Protection Level	V <sub>UV</sub>		11.0	-	12.5	V		
Under Voltage Protection Hysteresis	V <sub>H</sub>		0.2	0.5	-	V		
Alarm Signal Hold Time	t <sub>ALM(OC)</sub>	ALM-GND T <sub>c</sub> =-20~110°C	V <sub>CC</sub> ≥ 10V	1.0	2.0	2.4	ms	
	t <sub>ALM(UV)</sub>			2.5	4.0	4.9	ms	
	t <sub>ALM(TJOH)</sub>			5.0	8.0	11.0	ms	
Resistance for current limit	R <sub>ALM</sub>		960	1265	1570	Ω		

● Thermal Characteristics (T<sub>c</sub> = 25°C)

Items		Symbol	Min.	Typ.	Max.	Units
Junction to Case Thermal Resistance (*10)	Inverter	R <sub>th(j-c)Q</sub>	-	-	0.65	°C/W
	FWD	R <sub>th(j-c)D</sub>	-	-	1.30	°C/W
Case to Fin Thermal Resistance with Compound		R <sub>th(c-f)</sub>	-	0.05	-	°C/W

Note \*10: For 1device, the measurement point of the case is just under the chip.

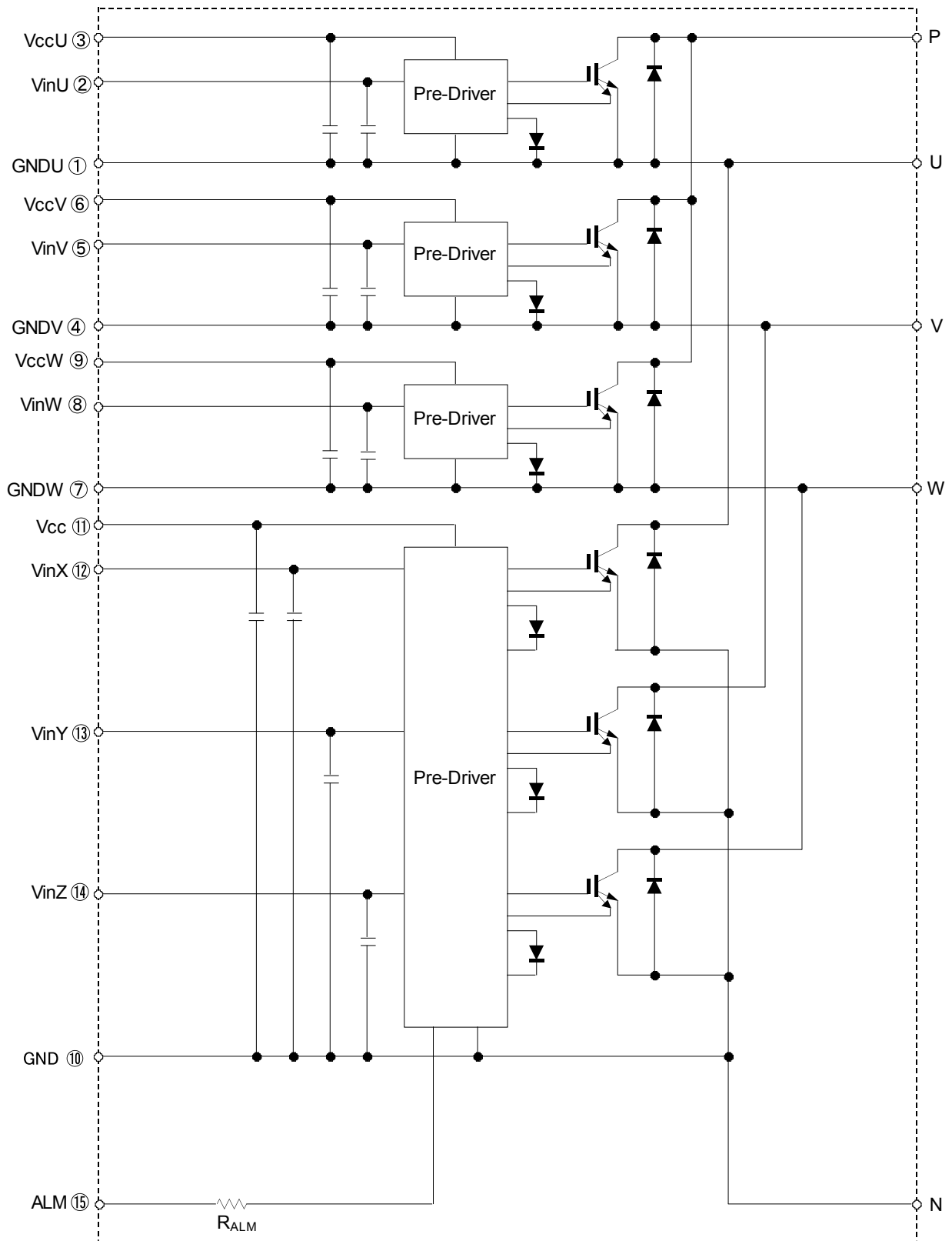
● Noise Immunity (V<sub>DC</sub>=300V, V<sub>CC</sub>=15V)

Items	Conditions	Min.	Typ.	Max.	Units
Common mode rectangular noise	Pulse width 1μs, polarity ±, 10 minute Judge : no over-current, no miss operating	±2.0	-	-	kV

● Recommended Operating Conditions

Items	Symbol	Min.	Typ.	Max.	Units
DC Bus Voltage	V <sub>DC</sub>	-	-	400	V
Power Supply Voltage of Pre-Driver	V <sub>CC</sub>	13.5	15.0	16.5	V
Arm shoot through blocking time for IPM's input signal	t <sub>dead</sub>	1.0	-	-	μs
Screw Torque (M4)	-	1.3	-	1.7	Nm

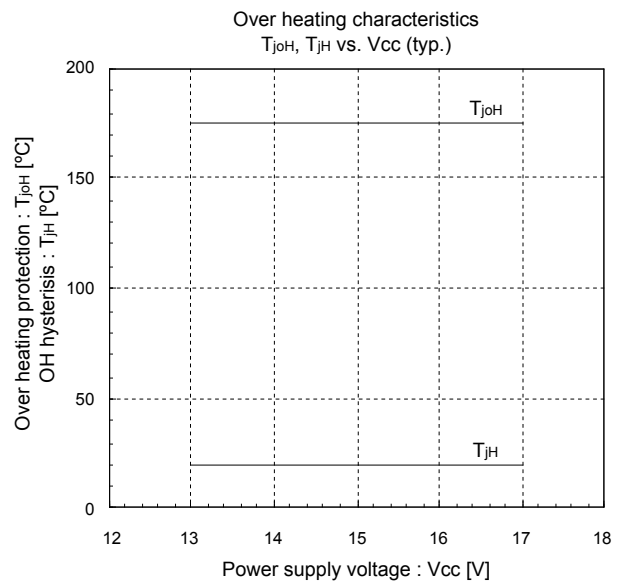
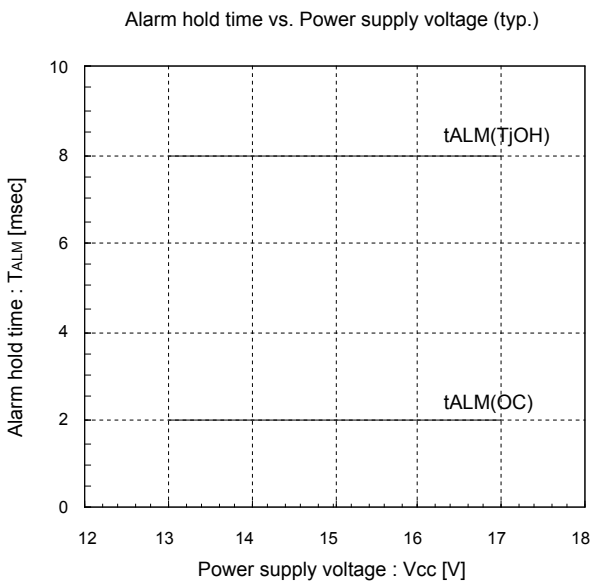
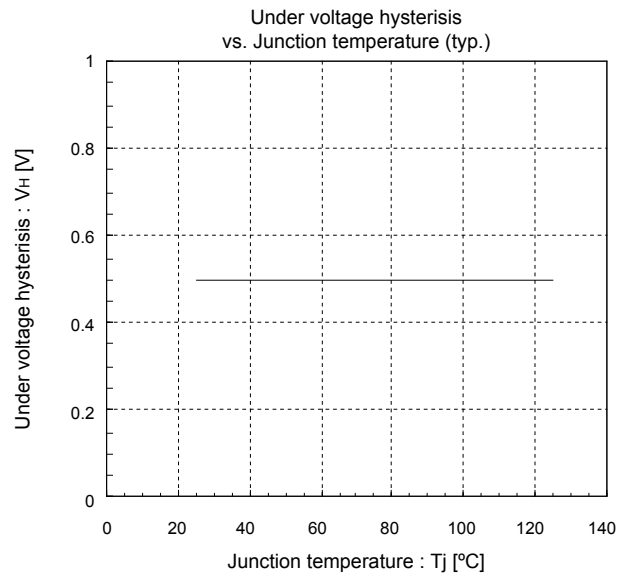
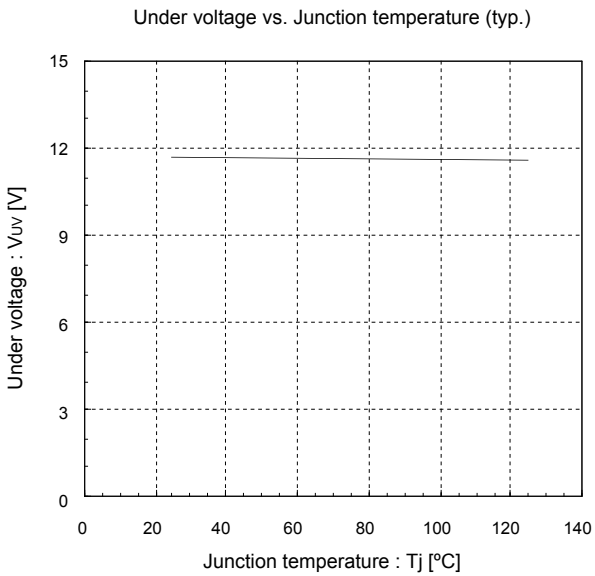
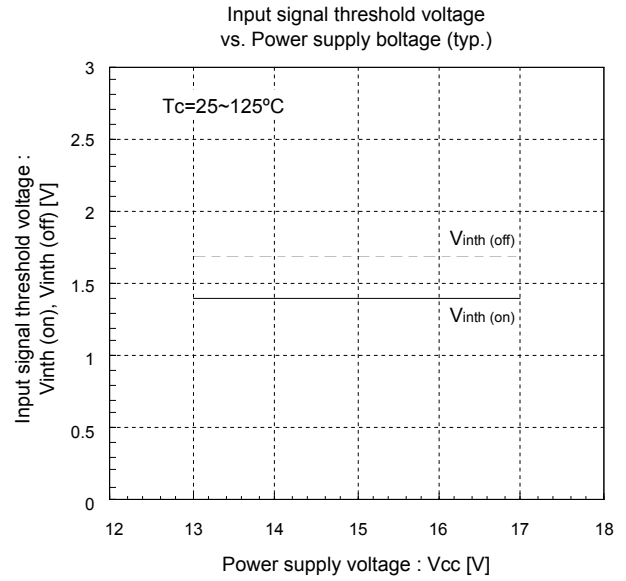
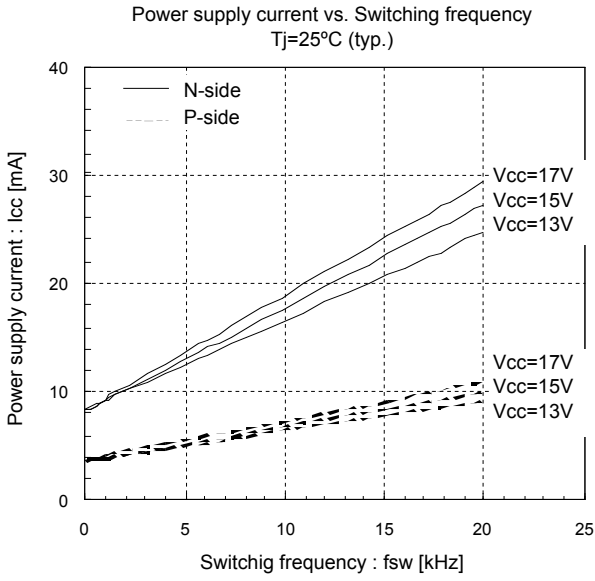
■ Block Diagram



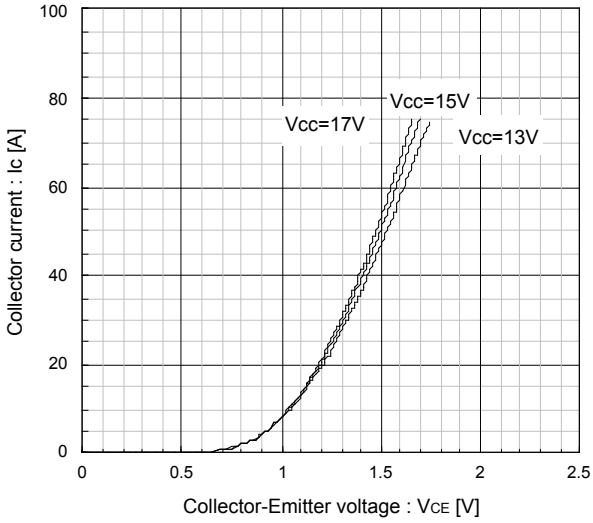
Pre-drivers include following functions

1. Amplifier for driver
2. Short circuit protection
3. Under voltage lockout circuit
4. Over current protection
5. IGBT chip over heating protection

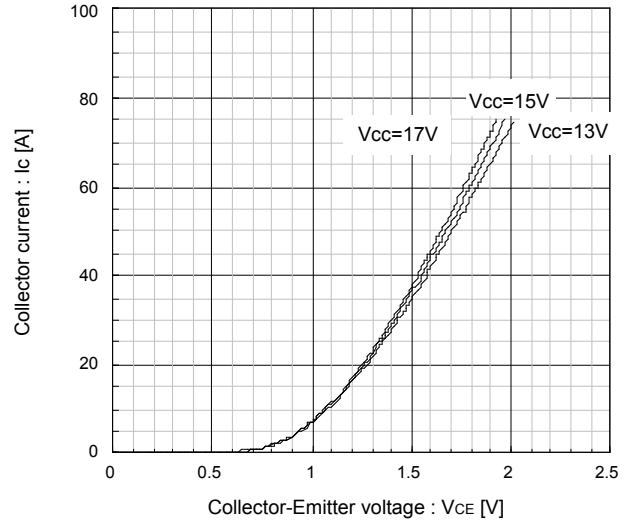
■ Characteristics (Representative)



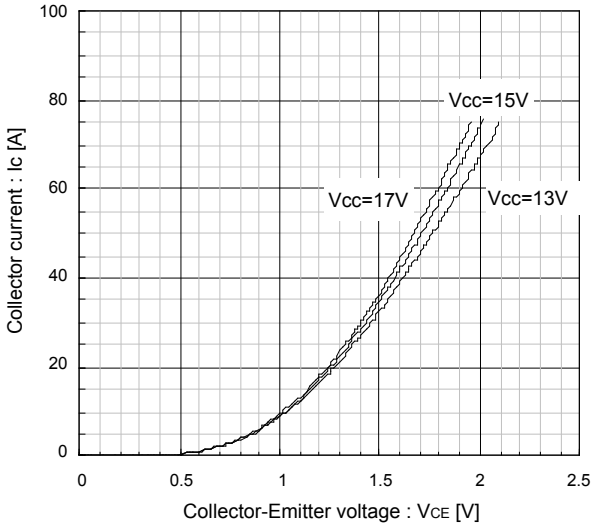
Collector current vs. collector-Emitter voltage  
T<sub>j</sub>=25°C [Chip] (typ.)



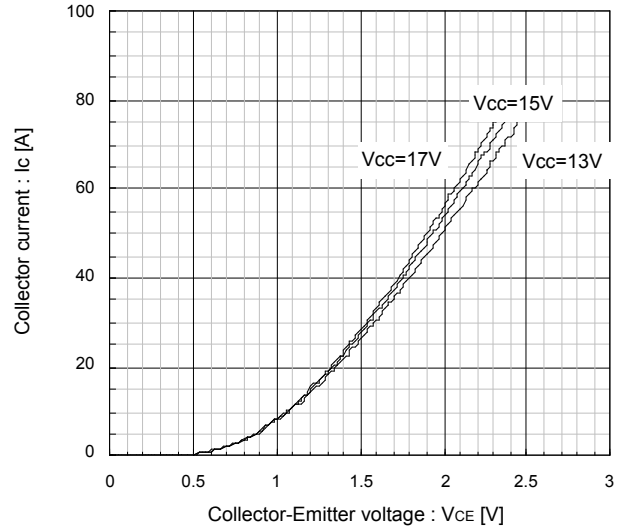
Collector current vs. collector-Emitter voltage  
T<sub>j</sub>=25°C [Terminal] (typ.)



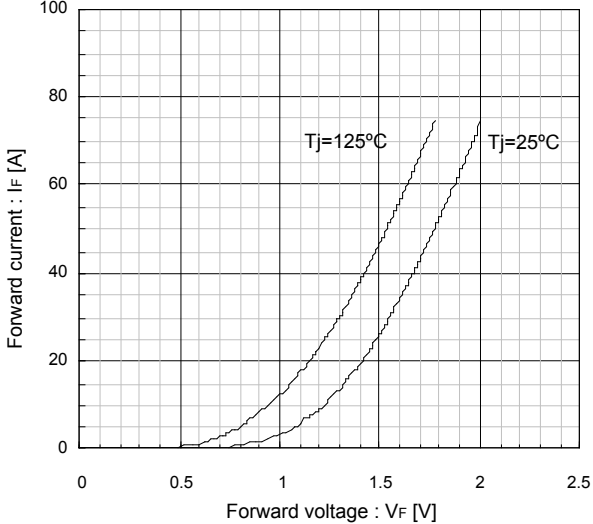
Collector current vs. collector-Emitter voltage  
T<sub>j</sub>=125°C [Chip] (typ.)



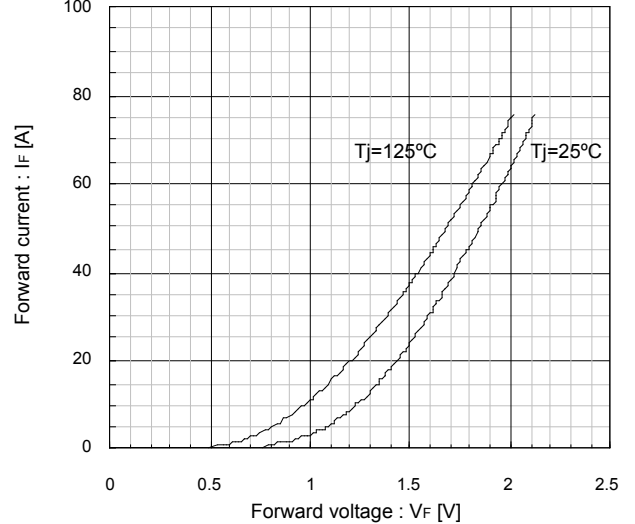
Collector current vs. collector-Emitter voltage  
T<sub>j</sub>=125°C [Terminal] (typ.)



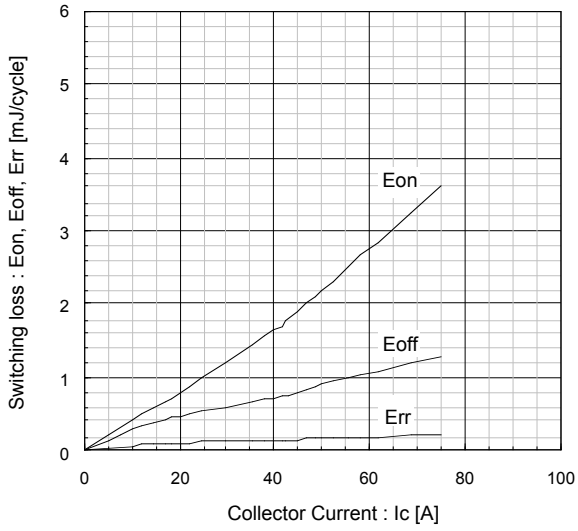
Forward current vs. Forward voltage  
[Chip] (typ.)



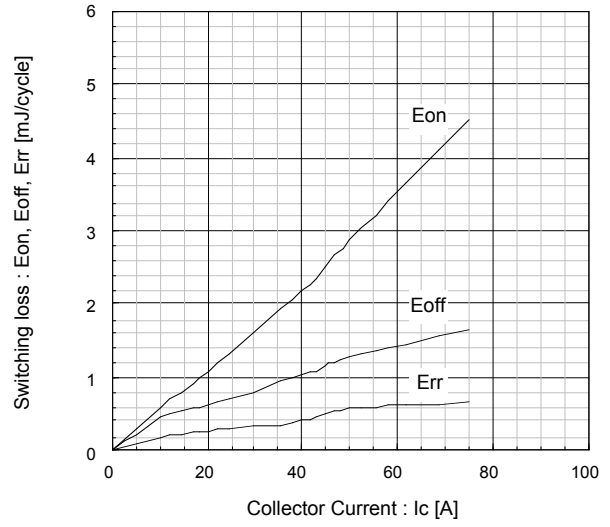
Forward current vs. Forward voltage  
[Terminal] (typ.)



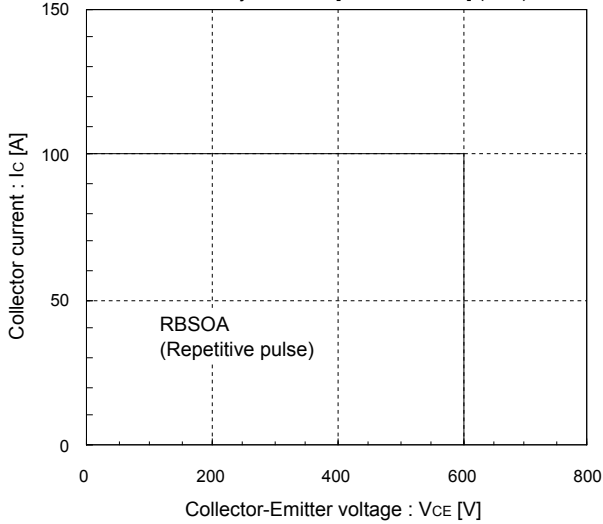
Switching Loss vs. Collector Current (typ.)  
 $V_{DC}=300V, V_{CC}=15V, T_j=25^\circ C$



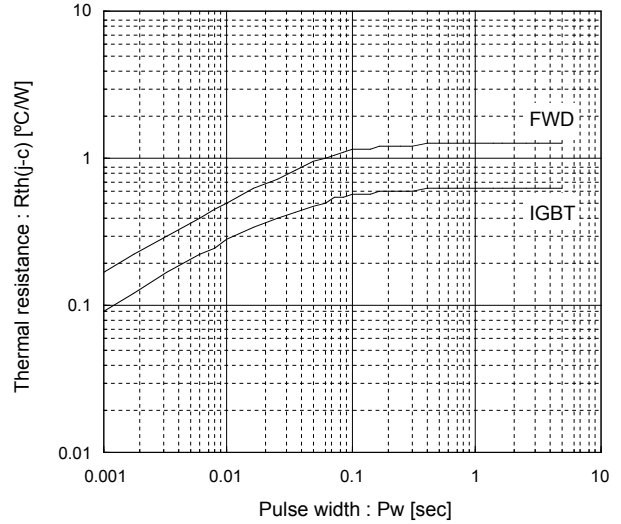
Switching Loss vs. Collector Current (typ.)  
 $V_{DC}=300V, V_{CC}=15V, T_j=125^\circ C$



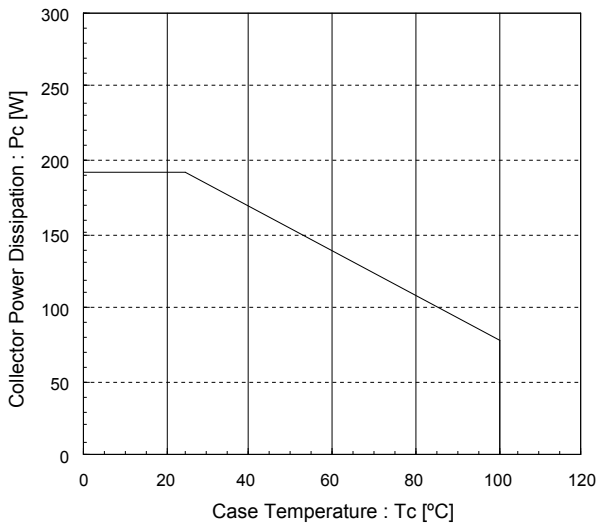
Reversed biased safe operating area  
 $V_{CC}=15V, T_j \le 125^\circ C$  [Main Terminal] (min.)



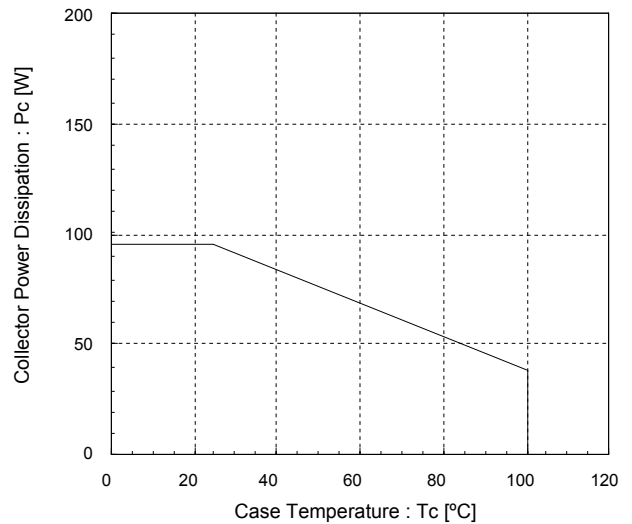
Transient thermal resistance (max.)

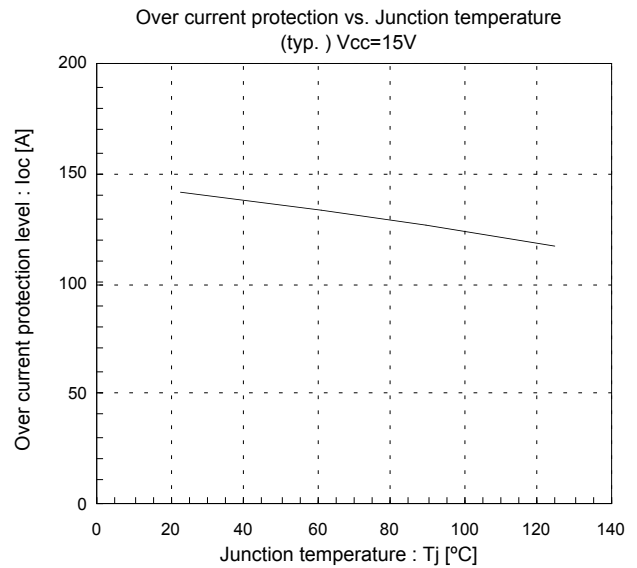
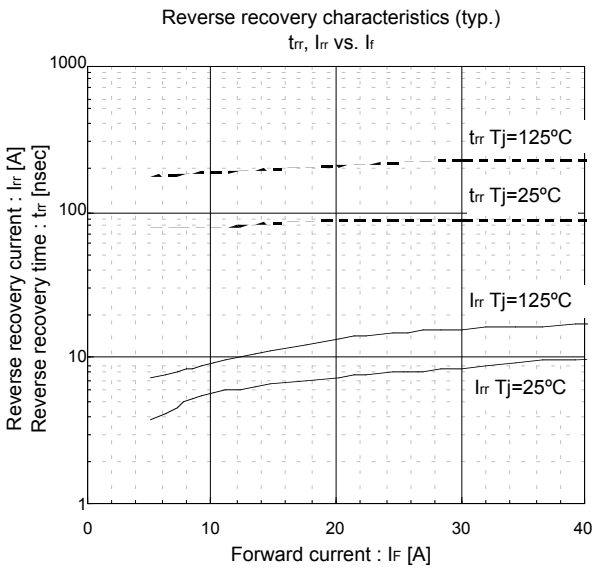
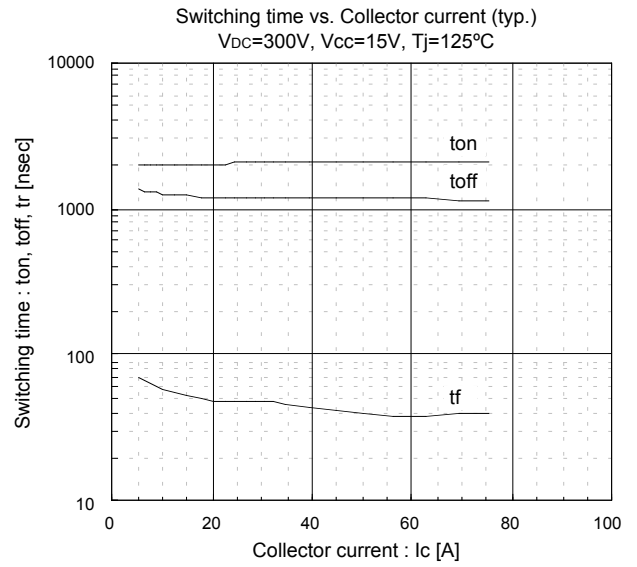
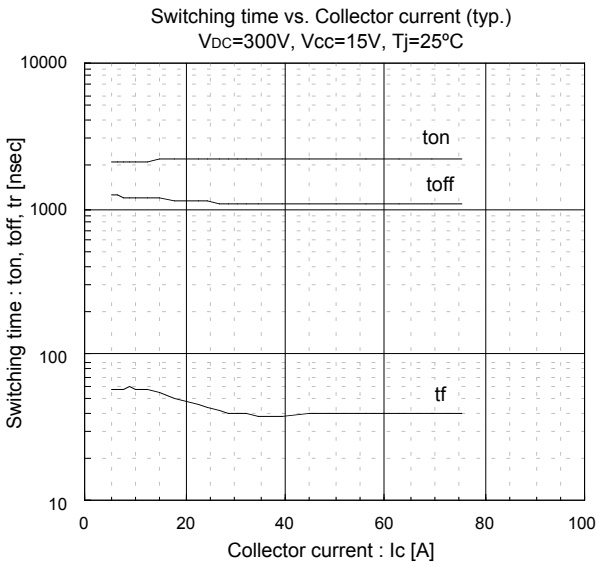


Power derating for IGBT (max.)  
 [per device]

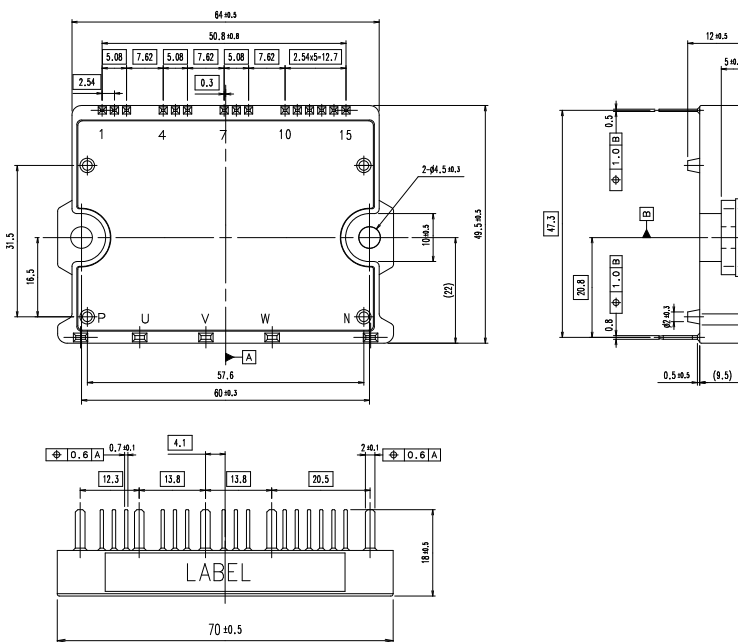


Power derating for FWD(max.)  
 [per device]





■ Outline Drawings, mm



**WARNING**

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  - Measurement equipment
  - Machine tools
  - Audiovisual equipment
  - Electrical home appliances
  - Personal equipment
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